MC100LVEL38

3.3V ECL ÷2, ÷4/6 Clock Generation Chip

ON Semiconductor®

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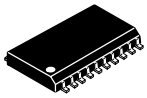
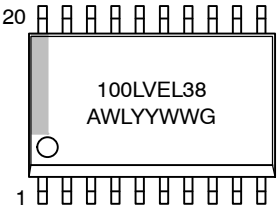


SO−20 WB
DW SUFFIX
CASE 751D

MARKING DIAGRAM*



A	= Assembly Location
WL	= Wafer Lot
YY	= Year
WW	= Work Week
G	= Pb−Free Package

*For additional marking information, refer to Application Note AND8002/D.

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 6 of this data sheet.

Description

The MC100LVEL38 is a low skew ÷2, ÷4/6 clock generation chip designed explicitly for low skew clock generation applications. The internal dividers are synchronous to each other, therefore, the common output edges are all precisely aligned. The device can be driven by either a differential or single-ended input signal.

The common enable ($\overline{EN}$) is synchronous so that the internal dividers will only be enabled/disabled when the internal clock is already in the LOW state. This avoids any chance of generating a runt clock pulse on the internal clock when the device is enabled/disabled as can happen with an asynchronous control. An internal runt pulse could lead to losing synchronization between the internal divider stages. The internal enable flip-flop is clocked on the falling edge of the input clock, therefore, all associated specification limits are referenced to the negative edge of the clock input.

The Phase_Out output will go HIGH for one clock cycle whenever the ÷2 and the ÷4/6 outputs are both transitioning from a LOW to a HIGH. This output allows for clock synchronization within the system.

Upon startup, the internal flip-flops will attain a random state; therefore, for systems which utilize multiple LVEL38s, the master reset (MR) input must be asserted to ensure synchronization. For systems which only use one LVEL38, the MR pin need not be exercised as the internal divider design ensures synchronization between the ÷2 and the ÷4/6 outputs of a single device.

The V_{BB} pin, an internally generated voltage supply, is available to this device only. For single-ended input conditions, the unused differential input is connected to V_{BB} as a switching reference voltage. V_{BB} may also rebias AC coupled inputs. When used, decouple V_{BB} and V_{CC} via a 0.01 μF capacitor and limit current sourcing or sinking to 0.5 mA. When not used, V_{BB} should be left open.

Features

- 50 ps Maximum Output-to-Output Skew
- Synchronous Enable/Disable
- Master Reset for Synchronization
- ESD Protection: >2 kV Human Body Model
- The 100 Series Contains Temperature Compensation
- PECL Mode Operating Range:
  V_{CC} = 3.0 V to 3.8 V with V_{EE} = 0 V
- NECL Mode Operating Range:
  V_{CC} = 0 V with V_{EE} = −3.0 V to −3.8 V
- Internal Input 75 kΩ Pulldown Resistors
- Meets or Exceeds JEDEC Spec EIA/JESD78 IC Latchup Test
- Moisture Sensitivity Pb = Level 1
  Pb−Free = Level 3
  For Additional Information, see Application Note AND8003/D
- Flammability Rating: UL 94 V−0 @ 0.125 in, Oxygen Index: 28 to 34
- Transistor Count = 388 devices
- Pb−Free Packages are Available*

*For additional information on our Pb−Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

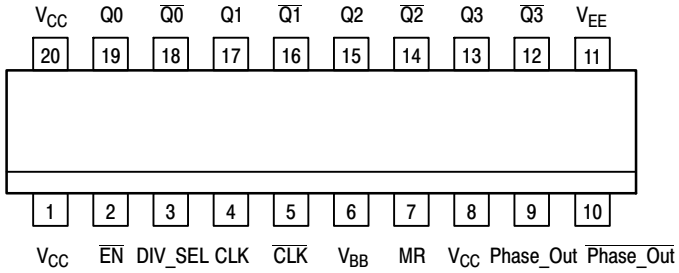


Figure 1. Pinout: 20-Lead SOIC (Top View)

Warning: All V_{CC} and V_{EE} pins must be externally connected to Power Supply to guarantee proper operation.

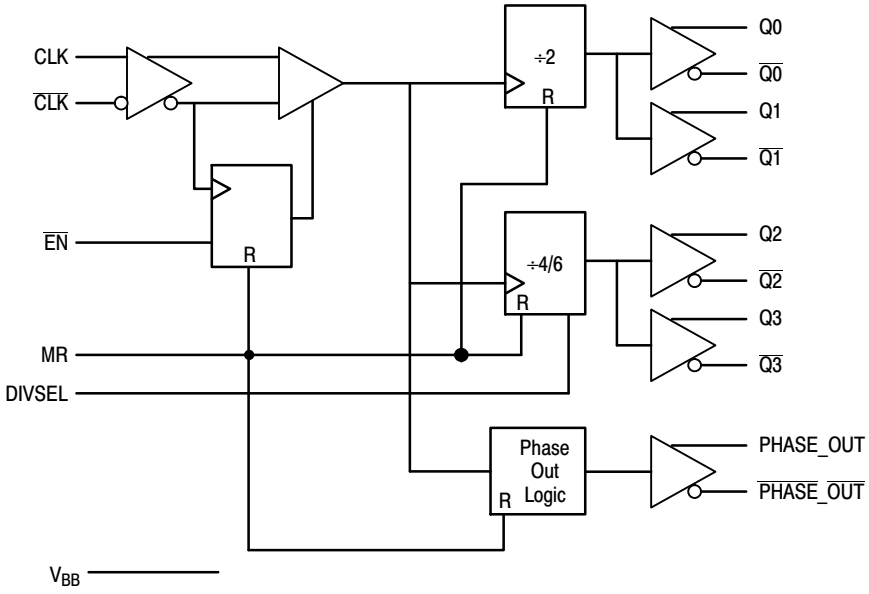


Figure 2. Logic Diagram

Table 1. PIN DESCRIPTION

Pin	Function
CLK, $\overline{CLK}$	ECL Diff Clock Inputs
Q_0, Q_1; $\overline{Q_0}$, $\overline{Q_1}$	ECL Diff ÷2 Outputs
Q_2, Q_3; $\overline{Q_2}$, $\overline{Q_3}$	ECL Diff ÷4/6 Outputs
$\overline{EN}$	ECL Sync Enable Input
MR	ECL Master Reset Input
DIVSEL	ECL Frequency Select Input
Phase_Out, $\overline{Phase\_Out}$	ECL Phase Sync Diff. Signal Output
V_{BB}	Reference Voltage Output
V_{CC}	Positive Supply
V_{EE}	Negative Supply

Table 2. FUNCTION TABLE

CLK	$\overline{EN}$	MR	Function
Z	L	L	Divide
ZZ	H	L	Hold Q_{0-3}
X	X	H	Reset Q_{0-3}

Z = Low-to-High Transition
ZZ = High-to-Low Transition
X = Don't Care

DVSEL	Q_2, Q_3 OUTPUTS
L	Divide by 4
H	Divide by 6

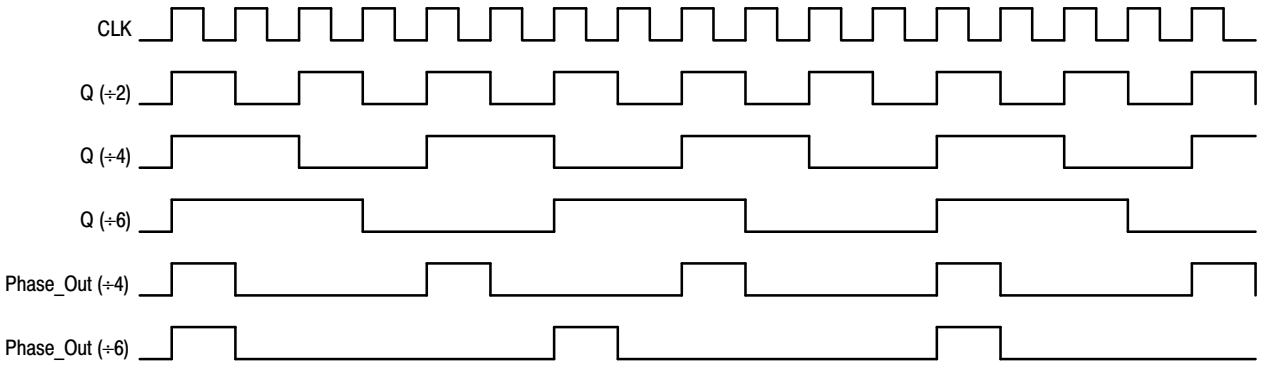


Figure 3. Timing Diagrams

Table 3. MAXIMUM RATINGS

Symbol	Parameter	Condition 1	Condition 2	Rating	Unit
V_{CC}	PECL Mode Power Supply	V_{EE} = 0 V		8 to 0	V
V_{EE}	NECL Mode Power Supply	V_{CC} = 0 V		−8 to 0	V
V_I	PECL Mode Input Voltage NECL Mode Input Voltage	V_{EE} = 0 V V_{CC} = 0 V	$V_I \leq V_{CC}$ $V_I \geq V_{EE}$	6 to 0 −6 to 0	V V
I_{out}	Output Current	Continuous Surge		50 100	mA mA
I_{BB}	V_{BB} Sink/Source			± 0.5	mA
T_A	Operating Temperature Range			−40 to +85	°C
T_{stg}	Storage Temperature Range			−65 to +150	°C
θ_{JA}	Thermal Resistance (Junction−to−Ambient)	0 lfpm 500 lfpm	SOIC−20 SOIC−20	90 60	°C/W °C/W
θ_{JC}	Thermal Resistance (Junction−to−Case)	Standard Board	SOIC−20	30 to 35	°C/W
T_{sol}	Wave Solder Pb Pb−Free	<2 to 3 sec @ 248°C <2 to 3 sec @ 260°C		265 265	°C

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Table 4. LVPECL DC CHARACTERISTICS V_{CC} = 3.3 V; V_{EE} = 0.0 V (Note 1)

Symbol	Characteristic	−40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{EE}	Power Supply Current		50	60		50	60		54	65	mA
V_{OH}	Output HIGH Voltage (Note 2)	2215	2295	2420	2275	2345	2420	2275	2345	2420	mV
V_{OL}	Output LOW Voltage (Note 2)	1470	1605	1745	1490	1595	1680	1490	1595	1680	mV
V_{IH}	Input HIGH Voltage (Single−Ended)	2135		2420	2135		2420	2135		2420	mV
V_{IL}	Input LOW Voltage (Single−Ended)	1490		1825	1490		1825	1490		1825	mV
V_{BB}	Output Voltage Reference	1.92		2.04	1.92		2.04	1.92		2.04	V
V_{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 6)	1.65		2.75	1.65		2.75	1.65		2.75	V
I_{IH}	Input HIGH Current			150			150			150	μA
I_{IL}	Input LOW Current	0.5			0.5			0.5			μA

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

1. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary ±0.3 V.
2. Outputs are terminated through a 50 Ω resistor to V_{CC} − 2.0 V.
3. V_{IHCMR} min varies 1:1 with V_{EE}, max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between $V_{PP\ Min}$ and 1.0 V.

Table 5. LVNECL DC CHARACTERISTICS V_{CC} = 0.0 V; V_{EE} = −3.3 V (Note 4)

Symbol	Characteristic	−40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
I_{EE}	Power Supply Current		50	60		50	60		54	65	mA
V_{OH}	Output HIGH Voltage (Note 5)	−1085	−1005	−880	−1025	−955	−880	−1025	−955	−880	mV
V_{OL}	Output LOW Voltage (Note 5)	−1830	−1695	−1555	−1810	−1705	−1620	−1810	−1705	−1620	mV
V_{IH}	Input HIGH Voltage (Single−Ended)	−1165		−880	−1165		−880	−1165		−880	mV
V_{IL}	Input LOW Voltage (Single−Ended)	−1810		−1475	−1810		−1475	−1810		−1475	mV
V_{BB}	Output Voltage Reference	−1.38		−1.26	−1.38		−1.26	−1.38		−1.26	V
V_{IHCMR}	Input HIGH Voltage Common Mode Range (Differential) (Note 6)	−1.65		−0.55	−1.65		−0.55	−1.65		−0.55	V
I_{IH}	Input HIGH Current			150			150			150	μA
I_{IL}	Input LOW Current	0.5			0.5			0.5			μA

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

4. Input and output parameters vary 1:1 with V_{CC}. V_{EE} can vary ±0.3 V.
5. Outputs are terminated through a 50 Ω resistor to V_{CC} − 2.0 V.
6. V_{IHCMR} min varies 1:1 with V_{EE}, max varies 1:1 with V_{CC}. The V_{IHCMR} range is referenced to the most positive side of the differential input signal. Normal operation is obtained if the HIGH level falls within the specified range and the peak-to-peak voltage lies between $V_{PP\ Min}$ and 1.0 V.

Table 6. AC CHARACTERISTICS V_{CC} = 3.3 V; V_{EE} = 0.0 V or V_{CC} = 0.0 V; V_{EE} = −3.3 V (Note 7)

Symbol	Characteristic	−40°C			25°C			85°C			Unit
		Min	Typ	Max	Min	Typ	Max	Min	Typ	Max	
fmax	Maximum Toggle Frequency (Figure 4) Divide by 2 Divide by 4, Divide by 6	 1.0 0.8	 1.2 0.82		 1.0 0.8	 1.2 0.82		 1.0 0.8	 1.2 0.82		GHz
t_{PLH} t_{PHL}	Propagation Delay to Output CLK to Q (Differential) CLK to Q (Single−Ended) CLK to Phase_Out (Differential) CLK to Phase_Out (Single−Ended) MR to.Q	 810 710 800 750 510		 1010 1010 1000 1050 810	 850 750 840 790 540		 1050 1050 1040 1090 840	 900 800 890 840 570		 1100 1100 1090 1140 870	ps
t_{SKEW}	Within-Device Skew (Note 8) $Q_0 - Q_3$ All			 50 75			 50 75			 50 75	ps
	Part-to-Part $Q_0 - Q_3$ (Differential) All			 200 240			 200 240			 200 240	
t_S	Setup Time $\overline{EN}$ to $\overline{CLK}$ DIVSEL to CLK	150			150			150			ps
t_H	Hold Time $\overline{CLK}$ to $\overline{EN}$ CLK to Div_Sel	150 200			150 200			150 200			ps
V_{PP}	Input Swing (Note 9) CLK	250		1000	250		1000	250		1000	mV
t_{RR}	Reset Recovery Time			100			100			100	ps
t_{PW}	Minimum Pulse Width CLK MR	800 700			800 700			800 700			ps
t_r, t_f	Output Rise/Fall Times Q (20% − 80%)	280		550	280		550	280		550	ps

NOTE: Device will meet the specifications after thermal equilibrium has been established when mounted in a test socket or printed circuit board with maintained transverse airflow greater than 500 lfpm. Electrical parameters are guaranteed only over the declared operating temperature range. Functional operation of the device exceeding these conditions is not implied. Device specification limit values are applied individually under normal operating conditions and not valid simultaneously.

7. V_{EE} can vary ±0.3 V.
8. Skew is measured between outputs under identical transitions.
9. V_{PP}(min) is minimum input swing for which AC parameters are guaranteed. The device will function reliably with differential inputs down to 100 mV.

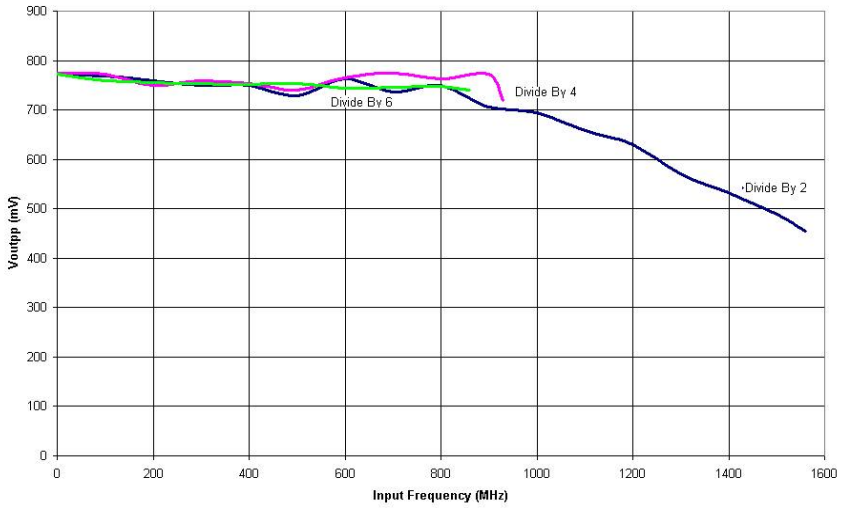


Figure 4. Fmax: Voutpp vs Input Frequency per DIV2/4/6

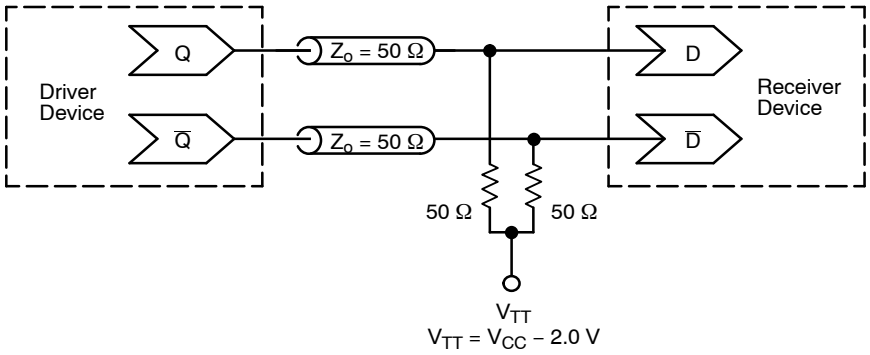


Figure 5. Typical Termination for Output Driver and Device Evaluation (See Application Note AND8020/D – Termination of ECL Logic Devices.)

ORDERING INFORMATION

Device	Package	Package†
MC100LVEL38DW	SOIC−20	38 Units / Rail
MC100LVEL38DWG	SOIC−20 (Pb−Free)	38 Units / Rail
MC100LVEL38DWR2	SOIC−20	1000 / Tape & Reel
MC100LVEL38DWR2G	SOIC−20 (Pb−Free)	1000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

Resource Reference of Application Notes

AN1405/D – ECL Clock Distribution Techniques

AN1406/D – Designing with PECL (ECL at +5.0 V)

AN1503/D – ECLinPS I/O SPiCE Modeling Kit

AN1504/D – Metastability and the ECLinPS Family

AN1568/D – Interfacing Between LVDS and ECL

AN1672/D – The ECL Translator Guide

AND8001/D – Odd Number Counters Design

AND8002/D – Marking and Date Codes

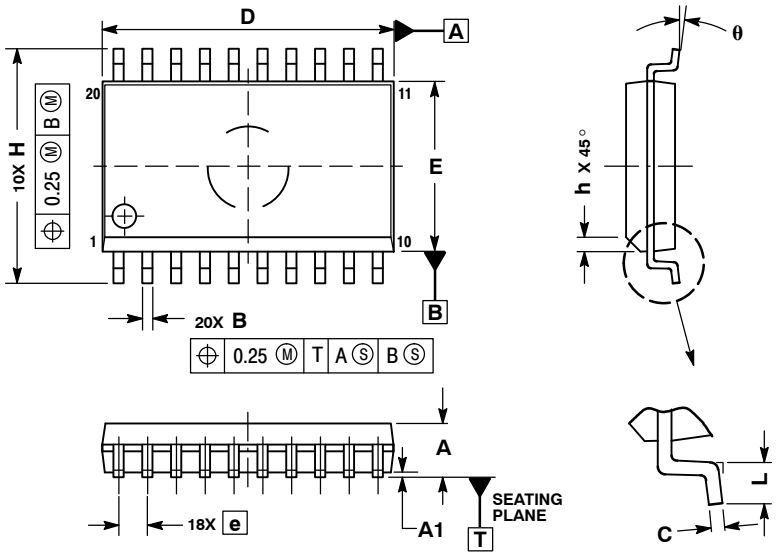
AND8020/D – Termination of ECL Logic Devices

AND8066/D – Interfacing with ECLinPS

AND8090/D – AC Characteristics of ECL Devices

PACKAGE DIMENSIONS

SO−20 WB
DW SUFFIX
CASE 751D−05
ISSUE G



NOTES:
1. DIMENSIONS ARE IN MILLIMETERS.
2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994.
3. DIMENSIONS D AND E DO NOT INCLUDE MOLD PROTRUSION.
4. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
5. DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS	
DIM	MIN	MAX
A	2.35	2.65
A1	0.10	0.25
B	0.35	0.49
C	0.23	0.32
D	12.65	12.95
E	7.40	7.60
e	1.27 BSC	
H	10.05	10.55
h	0.25	0.75
L	0.50	0.90
θ	0°	7°

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PUBLICATION ORDERING INFORMATION

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